

FDP045N10A / FDI045N10A N-Channel PowerTrench[®] MOSFET 100 V, 164 A, 4.5 m Ω

Features

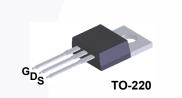
- $R_{DS(on)}$ = 3.8 m Ω (Typ.) @ V_{GS} = 10 V, I_D = 100 A
- · Fast Switching Speed
- Low Gate Charge, Q_G = 54 nC (Typ.)
- High Performance Trench Technology for Extremely Low $R_{\text{DS}(\text{on})}$
- High Power and Current Handling Capability
- RoHS Compliant

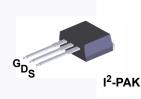
Description

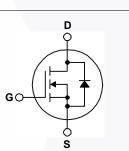
This N-Channel MOSFET is produced using Fairchild Semiconductor's advance PowerTrench[®] process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- · Motor drives and Uninterruptible Power Supplies
- Micro Solar Inverter







MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter	FDP045N10A_F102 FDI045N10A_F102	Unit V		
V _{DSS}	Drain to Source Voltage		100			
V _{GSS}	Gate to Source Voltage			±20	V	
ID		- Continuous (T _C = 25°C, Silicon Limited)		164*		
	Drain Current	- Continuous (T _C = 100 ^o C, Silicon LImited)		116	А	
		- Continuous (T _C = 25 ^o C, Pack	age Limited)	120	1	
I _{DM}	Drain Current	- Pulsed	(Note 1)	656	А	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		637	mJ		
dv/dt	Peak Diode Recovery dv/dt (Note 3)		6.0	V/ns		
P _D	Devues Dissinction	(T _C = 25°C)		263	W	
	Power Dissipation	- Derate Above 25°C		1.75	W/ ^o C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C		
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

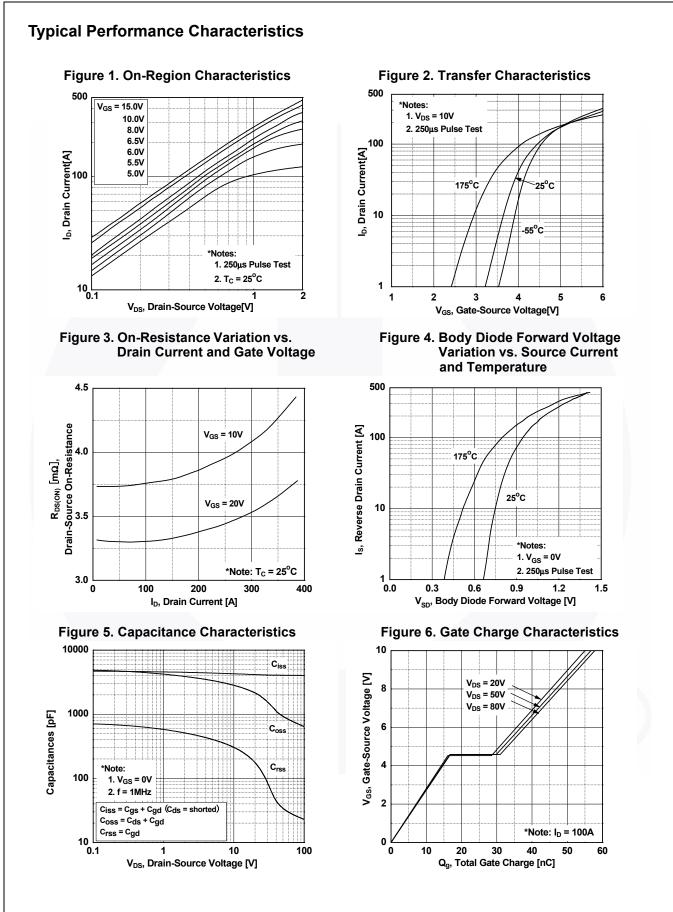
*Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 120A.

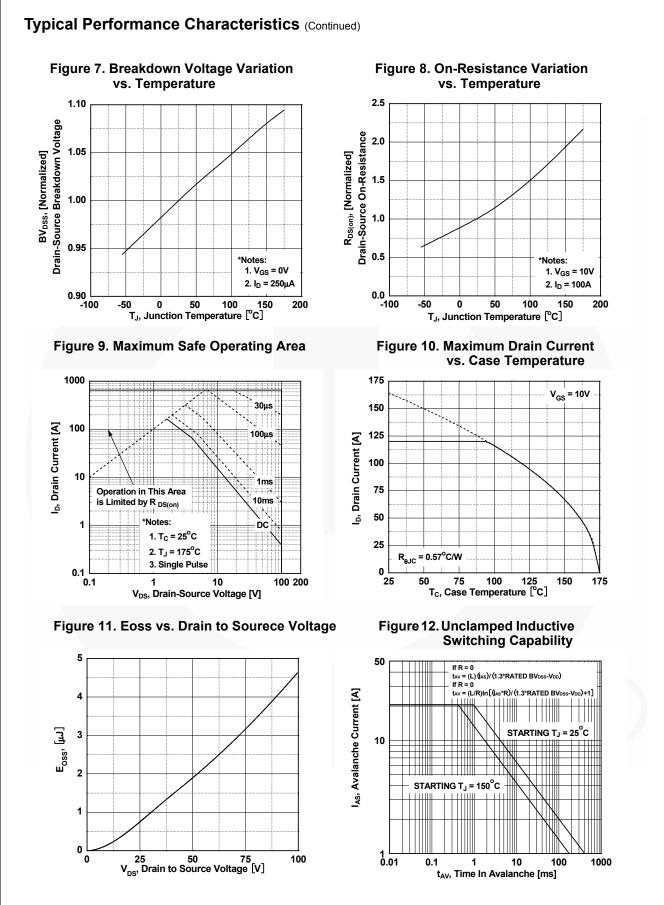
Thermal Characteristics

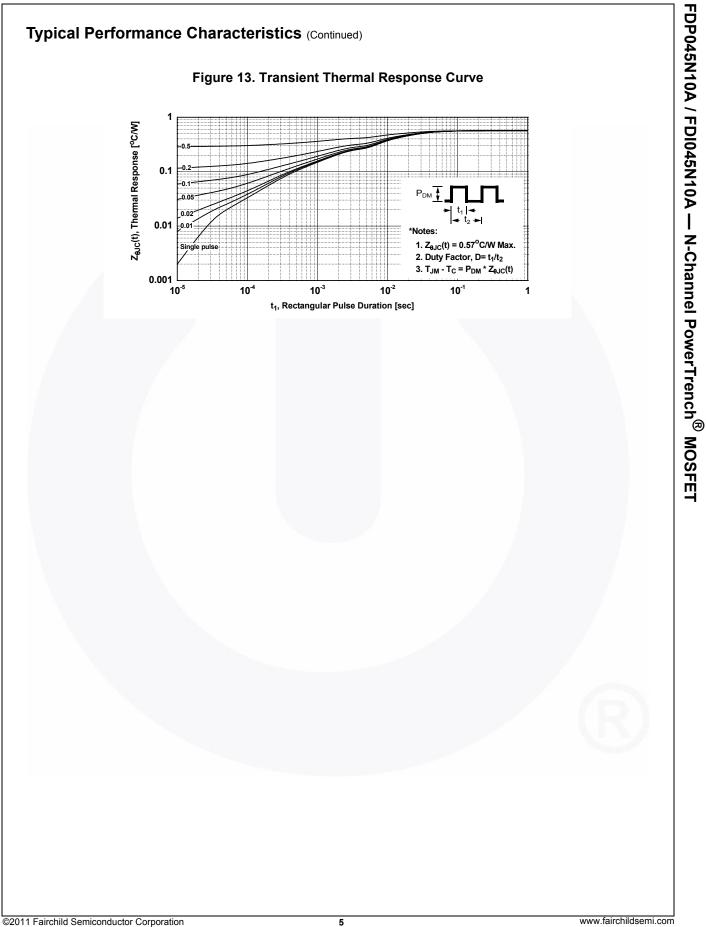
Symbol	Parameter	FDP045N10A_F102 FDI045N10A_F102	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.57	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max. 62		°C/W

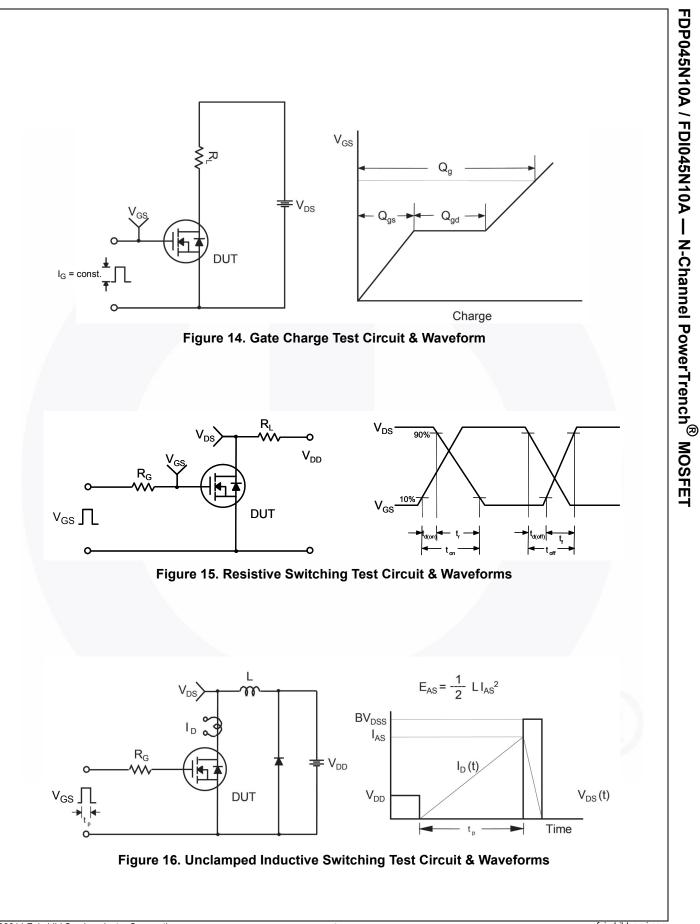
November 2013

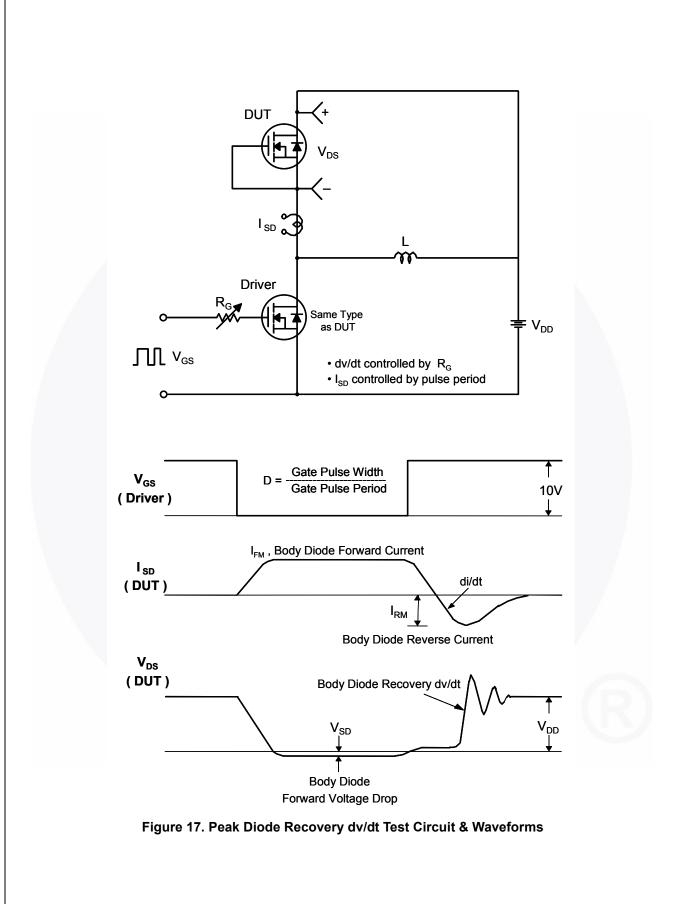
Part Number FDP045N10A_F102 FDI045N10A_F102		Top Mark	Package	Packing Method	Reel Size	Тар	e Width	Qua	ntity
		FDP045N10A	TO-220	Tube	N/A	N/A		50 units	
		FDI045N10A	I ² -PAK	Tube N/A		N/A		50 units	
Electrica	l Chara	cteristics T _C =	25ºC unless	otherwise noted.					
Symbol		Parameter		Test Condit	ions	Min.	Тур.	Max.	Unit
Off Charac	teristics	i							
BV _{DSS}	Drain to Source Breakdown Voltage		/oltage	I _D = 250 μA, V _{GS} = 0 V		100	-	-	V
ΔΒV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient		ure	$I_D = 250 \ \mu$ A, Referenced to 25° C		-	0.07	-	V/ºC
I _{DSS}	Zero Gat	Gate Voltage Drain Current		V _{DS} = 80 V, V _{GS} = 0 V		-	-	1	μA
		-		V _{DS} = 80 V, T _C = 150 ^o C		-	-	500	
I _{GSS}	Gate to Body Leakage Current		nt	$V_{GS} = \pm 20 V, V_{DS} = 0$	V	-	-	±100	nA
On Charac	teristics								
V _{GS(th)}	Gate Thr	eshold Voltage		V_{GS} = V_{DS} , I_D = 250 μ		2.0	-	4.0	V
R _{DS(on)}	Static Dra	ain to Source On Re	sistance	V _{GS} = 10 V, I _D = 100 A		-	3.8	4.5	mΩ
9 _{FS}	Forward	Transconductance		V _{DS} = 10 V, I _D = 100 A		-	132	-	S
Dynamic C	haracte	ristics							
C _{iss}	Input Ca	out Capacitance				-	3960	5270	pF
C _{oss}	Output C	apacitance		$-V_{DS} = 50 V, V_{GS} = 0 V$		-	925	1230	pF
C _{rss}	Reverse	Transfer Capacitance		f = 1 MHz		-	34	-	pF
C _{oss} (er)	Engry Re			V _{DS} = 50 V, V _{GS} = 0 V		-	1520	-	pF
Q _{q(tot)}	Total Gat	e Charge at 10V		$V_{GS} = 10 \text{ V}, V_{DS} = 50 \text{ V},$		-	54	74	nC
Q _{gs}	Gate to S	Source Gate Charge		$I_{\rm D} = 100 {\rm A}$		-	17	-	nC
Q _{gs2}		arge Threshold to Pla	ateau			-	8	-	nC
Q _{gd}		Drain "Miller" Charge		-	(Note 4)	-	13	-	nC
ESR	Equivale	ent Series Resistance (G-S)		f = 1 MHz		-	1.9	-	Ω
Switching	Charact	eristics							
		Delay Time					23	56	ns
t _{d(on)} t _r		On Rise Time Off Delay Time		$V_{DD} = 50 \text{ V}, \text{ I}_{D} = 100 \text{ A},$ $V_{GS} = 10 \text{ V}, \text{ R}_{G} = 4.7 \Omega$			26	62	ns
						7.	50	110	ns
t _{d(off)} t _f	Turn-Off			(Note 4)			15	40	ns
			-		(_		
I _s	1	e Characteristic		e Forward Current		-		164*	A
I _{SM}		um Pulsed Drain to Source Diode				-	-	656	A
V _{SD}		Source Diode Forward Voltage		$V_{GS} = 0 \text{ V}, I_{SD} = 100 \text{ A}$		-	-	1.3	V
t _{rr}		Recovery Time		$V_{GS} = 0 V, V_{DD} = 50 V, I_{SD} = 100 A,$		-	75	-	ns
Q _{rr}		Recovery Charge		$dl_{F}/dt = 100 \text{ A}/\mu\text{s}$		-	120		nC
2. L = 3 mH, I_{AS} = 3 3. $I_{SD} \le 100 \text{ A}, \text{ di/d}$	20.6 A, R _G = 2 t ≤ 200 A/µs, V	mited by maximum junction 5 Ω , starting T _J = 25°C. $'_{DD} \le BV_{DSS}$, starting T _J = 2 rating temperature typical c	5°C.					U	Y

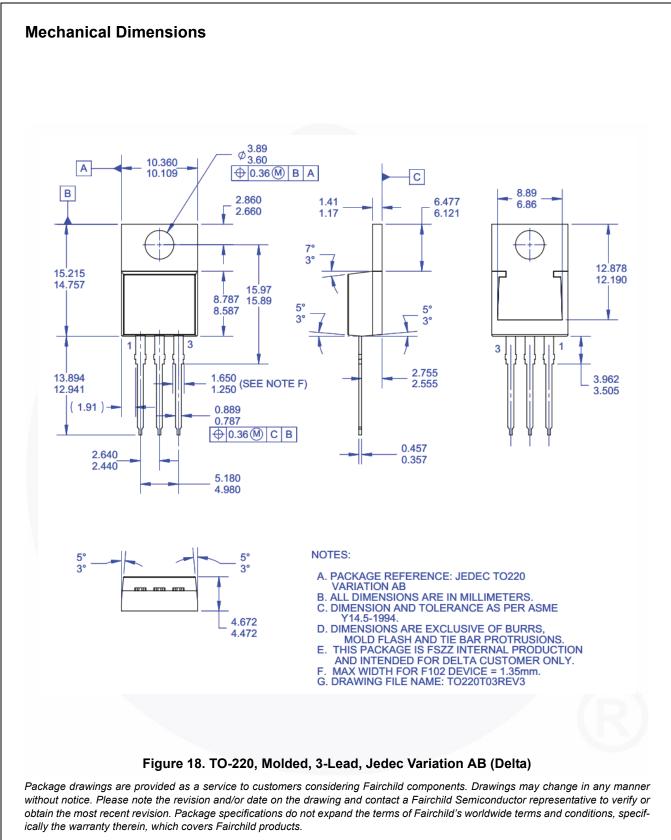






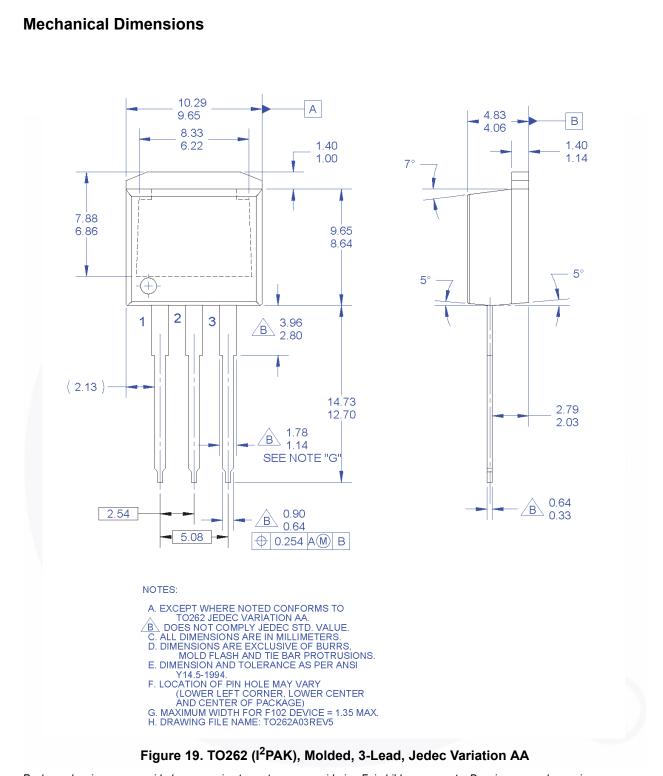






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FDP045N10A / FDI045N10A —

N-Channel PowerTrench[®] MOSFET

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